

TLP741J

- Office Machine
- Household Use Equipment
- Solid State Relay
- Switching Power Supply

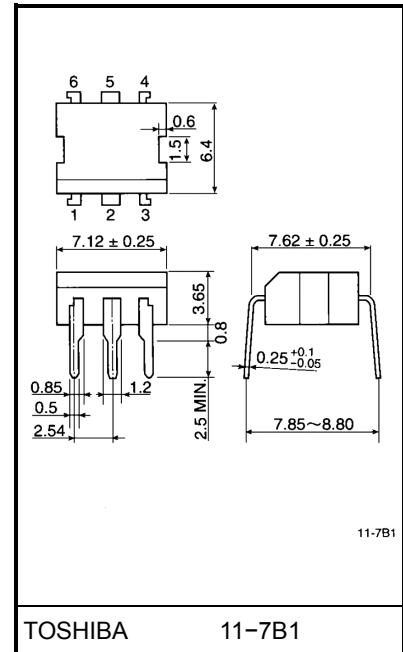
The TOSHIBA TLP741J consists of a photo-thyristor optically coupled to a gallium arsenide infrared emitting diode in a six lead plastic DIP package.

- Peak off-state voltage: 600 V (min.)
- Trigger LED current: 10 mA (max.)
- On-state current: 150 mA (max.)
- UL recognized: UL1577, file no. E67349
- BSI approved: BS EN60065: 1994
Certificate no. 6617
BS EN60950: 1992
Certificate no. 7366
Isolation voltage: 4000 V_{rms} (min.)
- Option (D4) type
VDE approved: DIN VDE0884 / 08,87
Certificate no. 65640
Maximum operating insulation voltage: 630 VPK
Highest permissible over voltage: 6000 VPK

(Note) When a VDE0884 approved type is needed, please designate the "option (D4)"

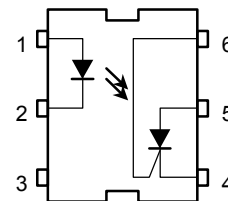
| | 7.62 mm pich standard type | 10.16 mm pich (LF2) type |
|-----------------------|-------------------------------|-----------------------------|
| • Creepage distance: | 7.0 mm (min.) | 8.0 mm (min.) |
| Clearance: | 7.0 mm (min.) | 8.0 mm (min.) |
| Insulation thickness: | 0.5 mm (min.) | 0.5 mm (min.) |

Unit in mm



Weight: 0.35 g

Pin Configuration (top view)



- 1 : ANODE
- 2 : CATHODE
- 3 : N.C.
- 4 : CATHODE
- 5 : ANODE
- 6 : GATE

Maximum Ratings (Ta = 25°C)

| Characteristic | | Symbol | Rating | Unit |
|--|--|-------------------------------|-----------|---------|
| LED | Forward current | I_F | 60 | mA |
| | Forward current derating (Ta ≥ 39°C) | $\Delta I_F / ^\circ\text{C}$ | -0.7 | mA / °C |
| | Peak forward current (100 μs pulse, 100 pps) | I_{FP} | 1 | A |
| | Power dissipation | P_D | 100 | mW |
| | Power dissipation derating (Ta ≥ 25°C) | $\Delta P_D / ^\circ\text{C}$ | -1.0 | mW / °C |
| | Reverse voltage | V_R | 5 | V |
| | Junction temperature | T_j | 125 | °C |
| Detector | Peak forward voltage (RGK = 27 kΩ) | V_{DRM} | 600 | V |
| | Peak reverse voltage (RGK = 27 kΩ) | V_{RRM} | 600 | V |
| | On-state current | $I_{T(RMS)}$ | 150 | mA |
| | On-state current derating (Ta ≥ 25°C) | $\Delta I_T / ^\circ\text{C}$ | -2.0 | mA / °C |
| | Peak on-state current (100μs pulse, 120 pps) | I_{TP} | 3 | A |
| | Peak one cycle surge current | I_{TSM} | 2 | A |
| | Peak reverse gate voltage | V_{GM} | 5 | V |
| | Power dissipation | P_D | 150 | mW |
| | Power dissipation derating (Ta ≥ 25°C) | $\Delta P_D / ^\circ\text{C}$ | -2.0 | mW / °C |
| | Junction temperature | T_j | 100 | °C |
| Storage temperature range | T_{stg} | -55~125 | °C | |
| Operating temperature range | T_{opr} | -55~100 | °C | |
| Lead soldering temperature (10 s) | T_{sol} | 260 | °C | |
| Total package power dissipation | P_T | 250 | mW | |
| Total package power dissipation derating (Ta ≥ 25°C) | $\Delta P_T / ^\circ\text{C}$ | -3.3 | mW / °C | |
| Isolation voltage (AC, 1 min., R.H. ≤ 60%) | BV_S | 4000 | V_{rms} | |

Recommended Operating Conditions

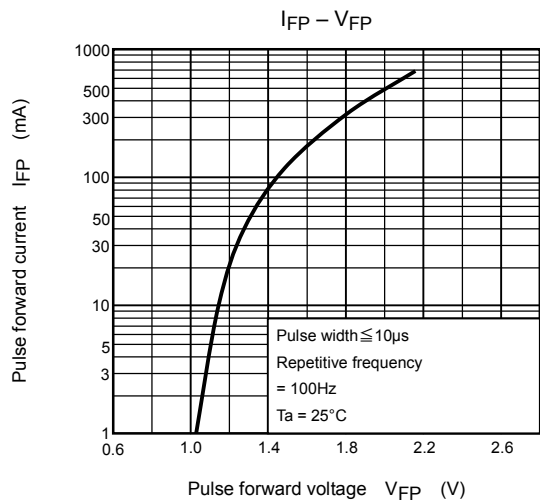
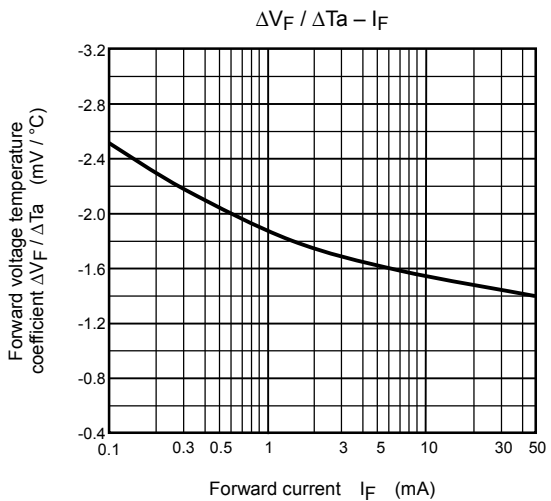
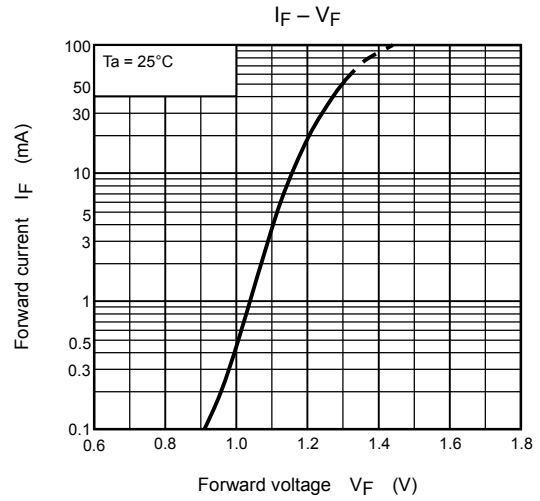
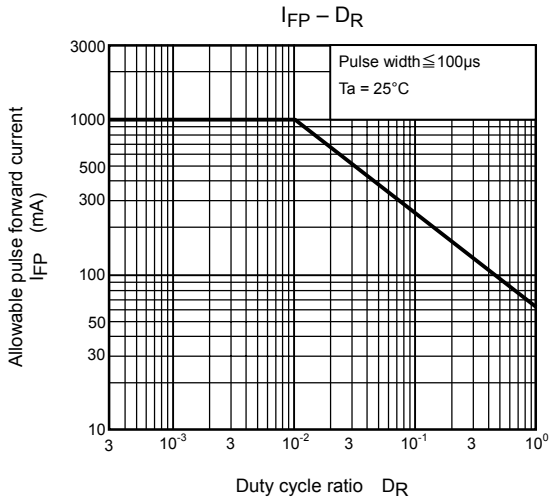
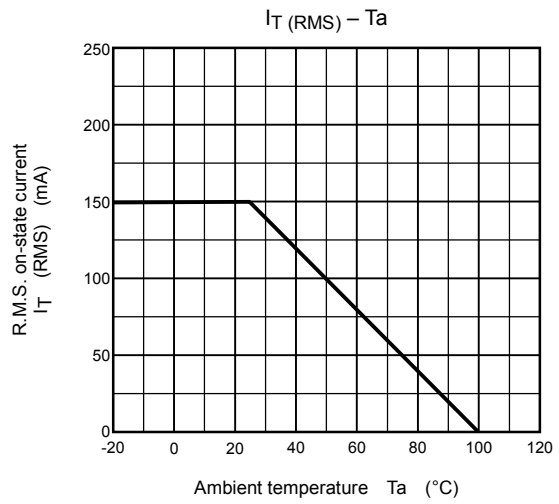
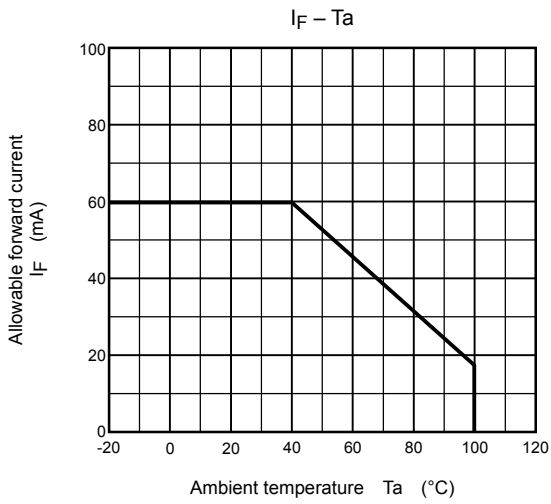
| Characteristic | Symbol | Min. | Typ. | Max. | Unit |
|----------------------------|-----------|------|------|------|----------|
| Supply voltage | V_{AC} | — | — | 240 | V_{ac} |
| Forward current | I_F | 15 | 20 | 25 | mA |
| Operating temperature | T_{opr} | -25 | — | 85 | °C |
| Gate to cathode resistance | R_{GK} | — | 10 | 27 | kΩ |
| Gate to cathode capacity | C_{GK} | — | 0.01 | 0.1 | μF |

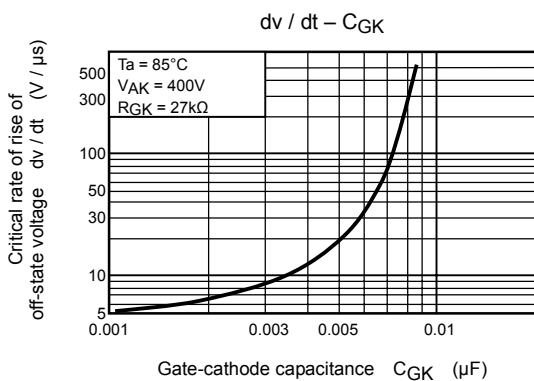
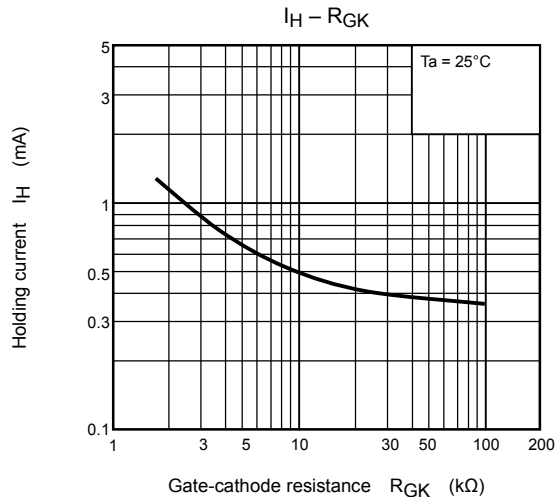
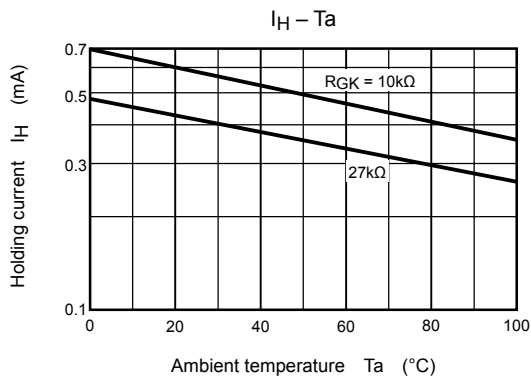
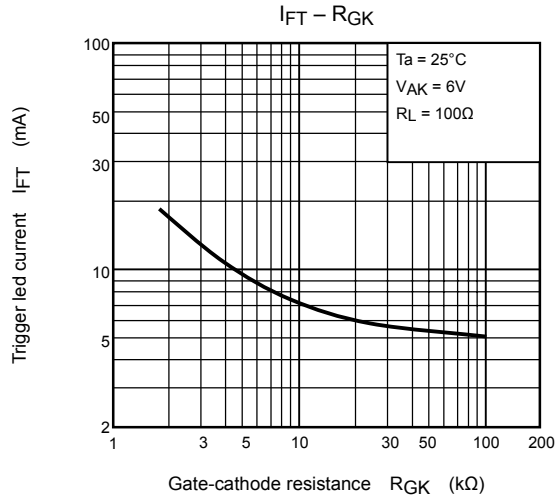
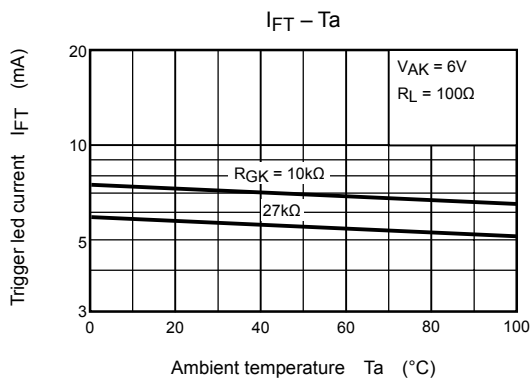
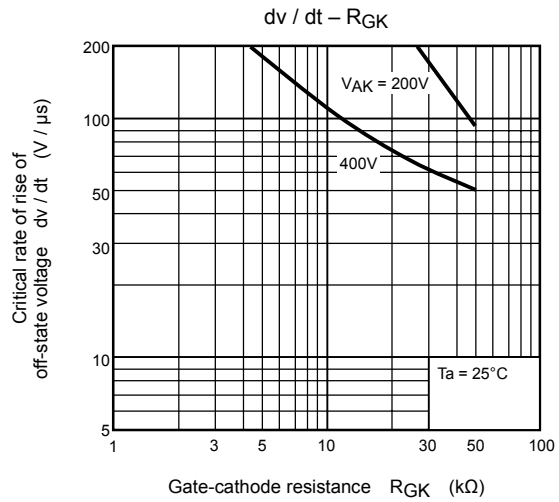
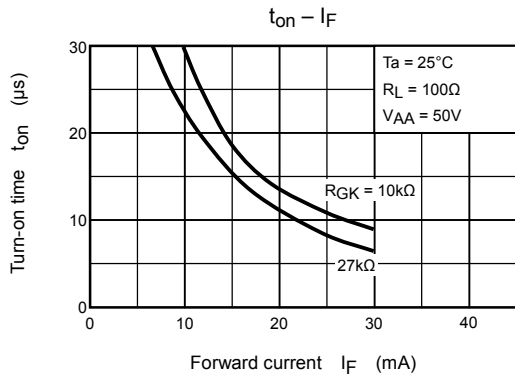
Individual Electrical Characteristics (Ta = 25°C)

| Characteristic | | Symbol | Test Condition | Min. | Typ. | Max. | Unit | |
|----------------|-------------------|----------------------------|---|-----------|------|------|------------------|---------------|
| LED | Forward voltage | V_F | $I_F = 10 \text{ mA}$ | 1.0 | 1.15 | 1.3 | V | |
| | Reverse current | I_R | $V_R = 5 \text{ V}$ | — | — | 10 | μA | |
| | Capacitance | C_T | $V = 0, f = 1 \text{ MHz}$ | — | 30 | — | pF | |
| Detector | Off-state current | I_{DRM} | $V_{AK} = 600 \text{ V}$ $R_{GK} = 27 \text{ k}\Omega$ | Ta = 25°C | — | 10 | 5000 | nA |
| | | | | Ta = 85°C | — | 1 | 150 | μA |
| | Reverse current | I_{RRM} | $V_{KA} = 600 \text{ V}$ $R_{GK} = 27 \text{ k}\Omega$ | Ta = 25°C | — | 10 | 5000 | nA |
| | | | | Ta = 85°C | — | 1 | 150 | μA |
| | On-state voltage | V_{TM} | $I_{TM} = 100 \text{ mA}$ | — | 0.9 | 1.3 | V | |
| | Holding current | I_H | $R_{GK} = 27 \text{ k}\Omega$ | — | 0.2 | — | mA | |
| | Off-state dv / dt | dv / dt | $V_{AK} = 420 \text{ V}, R_{GK} = 27 \text{ k}\Omega$ | — | 10 | — | V/ μs | |
| Capacitance | C_j | $V = 0, f = 1 \text{ MHz}$ | Anode to gate | — | 20 | — | pF | |
| | | | Gate to cathode | — | 350 | — | | |

Coupled Characteristics (Ta = 25°C)

| Characteristic | Symbol | Test Condition | Min. | Typ. | Max. | Unit |
|-------------------------------|----------|---|--------------------|-----------|------|-------------------|
| Trigger LED current | I_{FT} | $V_{AK} = 6 \text{ V}, R_{GK} = 27 \text{ k}\Omega$ | — | 5 | 10 | mA |
| Turn-on time | t_{ON} | $I_F = 30 \text{ mA}, V_{AA} = 50 \text{ V}$ $R_{GK} = 27 \text{ k}\Omega$ | — | 10 | — | μs |
| Coupled dv / dt | dv / dt | $V_S = 500 \text{ V}, R_{GK} = 27 \text{ k}\Omega$ | 500 | — | — | V / μs |
| Capacitance (input to output) | C_S | $V_S = 0, f = 1 \text{ MHz}$ | — | 0.8 | — | pF |
| Isolation resistance | R_S | $V_S = 500 \text{ V}$ | 1×10^{12} | 10^{14} | — | Ω |
| Isolation voltage | BV_S | AC, 1 minute | 4000 | — | — | V_{rms} |
| | | AC, 1 second, in oil | — | 10000 | — | |
| | | DC, 1 minute, in oil | — | 10000 | — | V_{dc} |





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